TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π–MOSV)

2SK2401

Chopper Regulator, DC-DC Converter and Motor Drive Applications

• Low drain-source ON resistance : $R_{DS (ON)} = 0.13 \Omega (typ.)$

High forward transfer admittance : |Y_{fs}| = 17 S (typ.)
 Low leakage current : I_{DSS} = 100 μA (max) (V_{DS} = 200 V)

• Enhancement mode : V_{th} = 1.5 to 3.5 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | | Symbol | Rating | Unit | |
|--|-----------------|------------------|------------|------|--|
| Drain-source voltage | | V_{DSS} | 200 | V | |
| Drain-gate voltage (R _{GS} = 20 kΩ) | | V_{DGR} | 200 | V | |
| Gate-source voltage | | V_{GSS} | ±20 | V | |
| Drain current | DC (Note 1) | ΙD | 15 | Α | |
| | Pulse (Note 1) | I _{DP} | 45 | Α | |
| Drain power dissipation (Tc = 25°C) | | P_{D} | 75 | W | |
| Single pulse avalanche energy (Note 2) | | E _{AS} | 166 | mJ | |
| Avalanche current | | I _{AR} | 15 | Α | |
| Repetitive avalanche | energy (Note 3) | E _{AR} | 7.5 | mJ | |
| Channel temperature | | T _{ch} | 150 | °C | |
| Storage temperature r | ange | T _{stg} | −55 to 150 | °C | |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|------------------------|------|--------|
| Thermal resistance, channel to case | R _{th (ch-c)} | 1.67 | °C/W |
| Thermal resistance, channel to ambient | R _{th (ch-a)} | 83.3 | °C / W |

Note 1: Ensure that the channel temperature does not exceed 150°C.

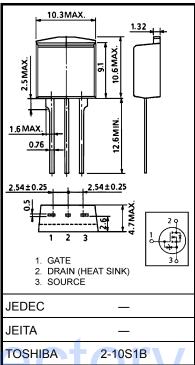
Note 2: $V_{DD} = 50 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$ (initial), L = 1.2 mH, $R_G = 25 \Omega$, $I_{AR} = 15 \text{ A}$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

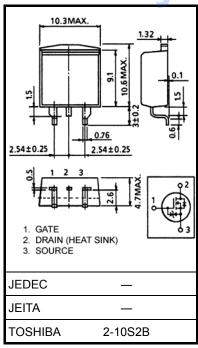
This transistor is an electrostatic-sensitive device.

Please handle with caution.





Weight: 1.5 g (typ.)



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Electrical Characteristics (Ta = 25°C)

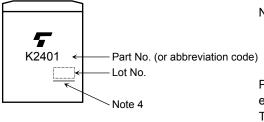
| Chara | cteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--|------------------|----------------------|---|-----|------|------|---------|
| Gate leakage cu | ırrent | I _{GSS} | V _{GS} = ±16 V, V _{DS} = 0 V | _ | _ | ±10 | μΑ |
| Drain cut-off cu | rrent | I _{DSS} | V _{DS} = 200 V, V _{GS} = 0 V | | _ | 100 | μA |
| Drain-source b | reakdown voltage | V (BR) DSS | I _D = 10 mA, V _{GS} = 0 V | 200 | _ | | V |
| Gate threshold | voltage | V _{th} | V _{DS} = 10 V, I _D = 1 mA | 1.5 | _ | 3.5 | V |
| Drain-source O | N resistance | R _{DS} (ON) | V _{GS} = 10 V, I _D = 10 A | | 0.13 | 0.18 | Ω |
| Forward transfe | r admittance | Y _{fs} | V _{DS} = 10 V, I _D = 10 A | 10 | 17 | | S |
| Input capacitano | ce | C _{iss} | | - | 2000 | 1 | |
| Reverse transfe | r capacitance | C _{rss} | C _{rss} V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz | | 200 | - | pF |
| Output capacitance | | Coss | | _ | 600 | - | |
| Switching time Fa | Rise time | t _r | $V_{GS} \stackrel{10 \text{ V}}{\text{O} \text{ V}} \stackrel{\text{ID}}{\text{ID}} = \stackrel{10 \text{ A}}{\text{V}} \stackrel{\text{Out}}{\text{V}} \stackrel{\text{C}}{\text{U}} \stackrel{\text{ID}}{\text{V}} = 100 \text{ V}$ | _ | 35 | _ | |
| | Turn-on time | t _{on} | | _ | 50 | _ | 20 |
| | Fall time | t _f | | _ | 10 | _ | ns |
| | Turn-off time | t _{off} | Duty $\leq 1\%$, $t_{\mathbf{w}} = 10 \ \mu s$ | _ | 66 | _ | |
| Total gate charge (Gate-source plus gate-drain) | | Qg | | _ | 40 | | |
| Gate-source charge | | Q _{gs} | $V_{DD} \approx 100 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 15 \text{ A}$ | | 25 | | nC - |
| Gate-drain ("miller") charge | | Q_{gd} | | | 15 | _ | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------|---|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I _{DR} | _ | _ | _ | 15 | Α |
| Pulse drain reverse current (Note 1) | I _{DRP} | _ | _ | _ | 45 | Α |
| Forward voltage (diode) | V _{DSF} | I _{DR} = 15 A, V _{GS} = 0 V | _ | _ | -2.0 | V |
| Reverse recovery time | t _{rr} | I _{DR} = 15 A, V _{GS} = 0 V | | 180 | | ns |
| Reverse recovery charge | Q _{rr} | dI _{DR} / dt = 100 A / μs | | 1.13 | | μC |

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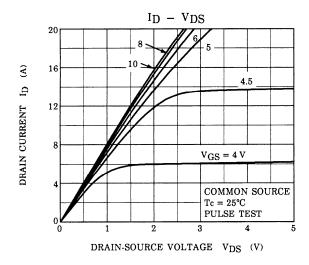
Marking

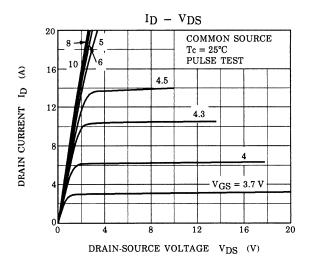


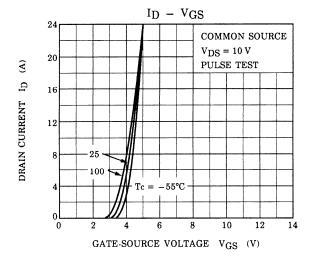
Note 4: A line under a Lot No. identifies the indication of product Labels.

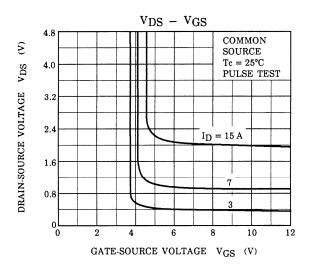
Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

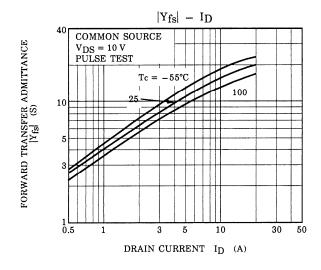
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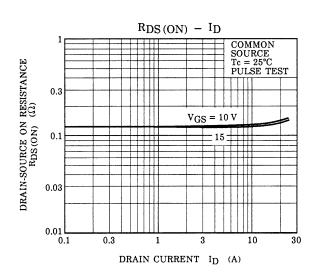


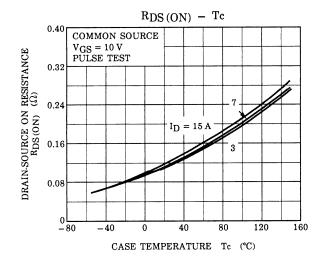


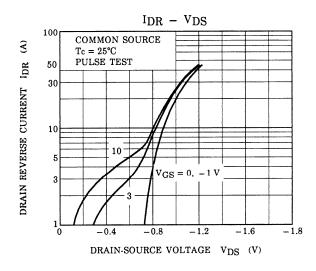


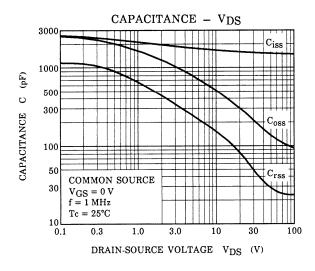


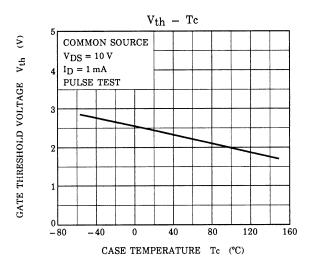


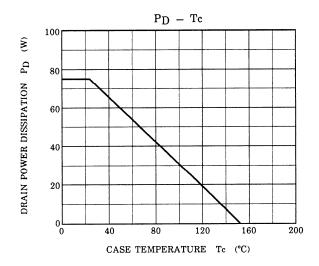


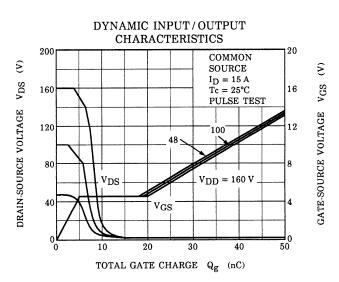




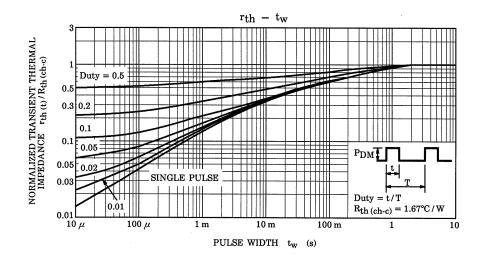


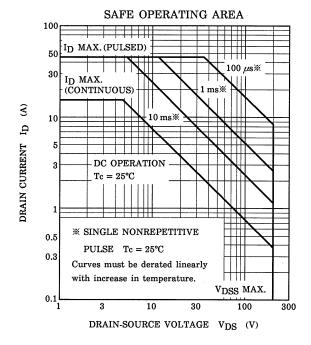


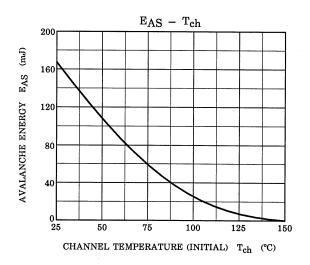


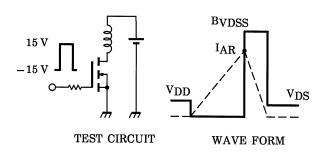


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$$R_G$$
 = 25 Ω V_{DD} = 50 V, L = 1.2 mH

$$EAS = \frac{1}{2} \cdot L \cdot I^{2} \cdot \left(\frac{BVDSS}{BVDSS - VDD} \right)$$

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